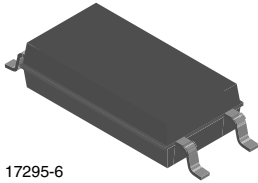
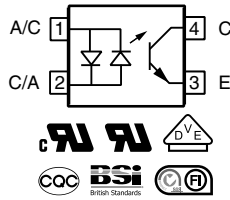


Optocoupler, Phototransistor Output, AC Input, Low Input Current, 4 Pin LSOP, Long Creepage Mini-Flat Package



17295-6


FEATURES

- Low profile package
- High collector emitter voltage, $V_{CEO} = 80\text{ V}$
- Isolation test voltage, 5000 V_{RMS}
- Low coupling capacitance
- High common mode transient immunity
- Material categorization:
For definitions of compliance please see www.vishay.com/doc?99912


DESCRIPTION

The VOL628A has two GaAs infrared emitting diodes, which are optically coupled to a silicon planar phototransistor detector, and are incorporated in a 4 pin LSOP wide body package.

It features a high current transfer ratio, low coupling capacitance, and high isolation voltage.

The coupling device is designed for signal transmission between two electrically separated circuits.

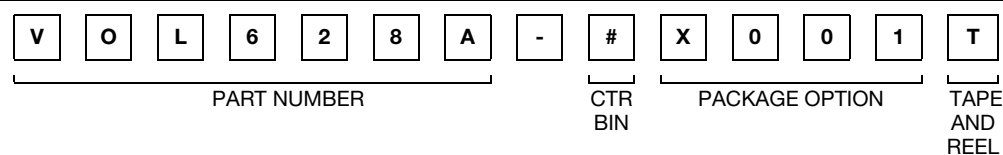
APPLICATIONS

- Telecom
- Industrial controls
- Battery powered equipment
- Office machines
- Programmable controllers

AGENCY APPROVALS

(All parts are certified under base model VOL628A)

- UL1577, file no. E76222
- cUL CSA 22.2 bulletin 5A, double protection
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- BSI: EN 60065:2002, EN 60950-1:2006
- FIMKO EN60950-1
- CQC: GB8898-2011, GB4943.1-2011

ORDERING INFORMATION


AGENCY CERTIFIED/PACKAGE	CTR (%)			
	1 mA			
UL, cUL, BSI, FIMKO, CQC	50 to 600	40 to 80	63 to 125	100 to 200
4 pin LSOP, mini-flat, long creepage	VOL628AT	VOL628A-1T	VOL628A-2T	VOL628A-3T
UL, cUL, BSI, FIMKO, CQC, VDE (option 1)	50 to 600	40 to 80	63 to 125	100 to 200
4 pin LSOP, mini-flat, long creepage	VOL628A-X001T	VOL628A-1X001T	VOL628A-2X001T	VOL628A-3X001T

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V_R	6	V
Power dissipation		P_{diss}	100	mW
Forward current		I_F	± 60	mA
Junction temperature		T_j	125	$^{\circ}\text{C}$
OUTPUT				
Collector emitter voltage		V_{CEO}	80	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
	$t_p/T = 0.5, t_p < 10\text{ ms}$	I_C	100	mA
Power dissipation		P_{diss}	150	mW
Junction temperature		T_j	125	$^{\circ}\text{C}$
COUPLER				
Isolation test voltage between emitter and detector	$t = 1\text{ min}$	V_{ISO}	5000	V_{RMS}
Total power dissipation		P_{tot}	250	mW
Storage temperature range		T_{stg}	- 55 to + 125	$^{\circ}\text{C}$
Ambient temperature range		T_{amb}	- 55 to + 110	$^{\circ}\text{C}$
Soldering temperature ⁽¹⁾	$\leq 10\text{ s}$	T_{sld}	260	$^{\circ}\text{C}$

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- ⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices.

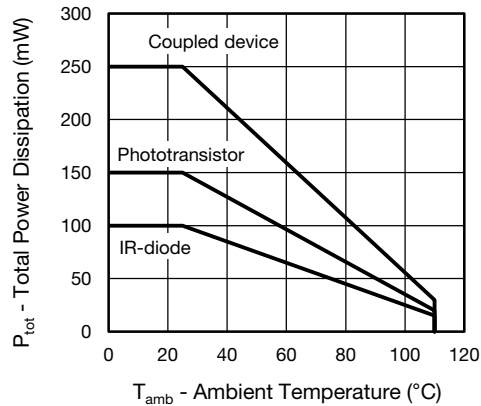


Fig. 1 - Total Power Dissipation vs. Ambient Temperature

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = \pm 5\text{ mA}$		V_F		1.16	1.5	V
Reverse current	$V_R = 6\text{ V}$		I_R			100	μA
Capacitance	$V_R = 0\text{ V}, f = 1\text{ MHz}$		C_O		45		pF
OUTPUT							
Collector emitter leakage current	$V_{CE} = 10\text{ V}, I_F = 0\text{ A}$		I_{CEO}		10	200	nA
Collector emitter capacitance	$V_{CE} = 5\text{ V}, f = 1\text{ MHz}$		C_{CE}		7		pF
COUPLER							
Collector emitter saturation voltage	$I_C = 0.2\text{ mA}, I_F = \pm 1\text{ mA}$	VOL628A	V_{CEsat}		0.25	0.4	V
	$I_C = 0.2\text{ mA}, I_F = \pm 1\text{ mA}$	VOL628A-1T	V_{CEsat}		0.25	0.4	V
	$I_C = 0.32\text{ mA}, I_F = \pm 1\text{ mA}$	VOL628A-2T	V_{CEsat}		0.25	0.4	V
	$I_C = 0.5\text{ mA}, I_F = \pm 1\text{ mA}$	VOL628A-3T	V_{CEsat}		0.25	0.4	V
Coupling capacitance	$f = 1\text{ MHz}$		C_C		0.25		pF

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I_C/I_F	$I_F = \pm 1\text{ mA}$, $V_{CE} = 5\text{ V}$	VOL628A	CTR	50		600	%
		VOL628A-1	CTR	40		80	%
		VOL628A-2	CTR	63		125	%
		VOL628A-3	CTR	100		200	%

SWITCHING CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn on time	$V_{CC} = 5\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\text{ }\Omega$	t_{on}		6		μs
Rise time	$V_{CC} = 5\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\text{ }\Omega$	t_r		3.5		μs
Turn off time	$V_{CC} = 5\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\text{ }\Omega$	t_{off}		5.5		μs
Fall time	$V_{CC} = 5\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\text{ }\Omega$	t_f		5		μs

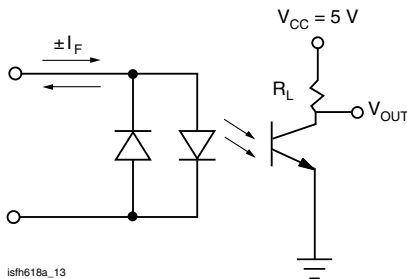


Fig. 2 - Test Circuit

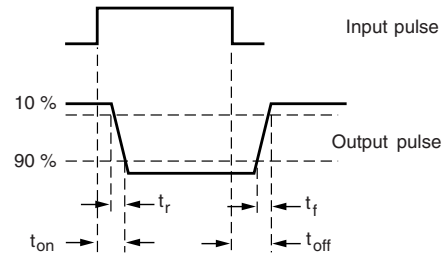


Fig. 3 - Test Circuit and Waveforms

SAFETY AND INSULATION RATED PARAMETERS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Partial discharge test voltage - routine test	100 %, $t_{test} = 1\text{ s}$	V_{pd}	2			kV_{peak}
Partial discharge test voltage - lot test (sample test)	$t_{Tr} = 60\text{ s}$, $t_{test} = 10\text{ s}$, (see figure 4)	V_{IOTM}			8	kV_{peak}
		V_{pd}	1.68			kV_{peak}
Insulation voltage		V_{IORM}			1050	V_{peak}
Insulation resistance	$V_{IO} = 500\text{ V}$, $T_{amb} = 25\text{ }^{\circ}\text{C}$	R_{IO}	10^{12}			Ω
	$V_{IO} = 500\text{ V}$, $T_{amb} = 100\text{ }^{\circ}\text{C}$	R_{IO}	10^{11}			Ω
	$V_{IO} = 500\text{ V}$, $T_{amb} = 150\text{ }^{\circ}\text{C}$ (construction test only)	R_{IO}	10^9			Ω
Safety rating - maximum input current		I_{si}			130	mA
Safety rating - maximum power dissipation		P_{SO}			265	mW
Safety rating - maximum ambient temperature		T_{si}			150	$^{\circ}\text{C}$
Clearance distance			8			mm
Creepage distance			8			mm
Insulation distance (internal)			0.4			mm

Note

- According to DIN EN 60747-5-5 (VDE 0884), § 7.4.3.8.2, (see figure 4). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

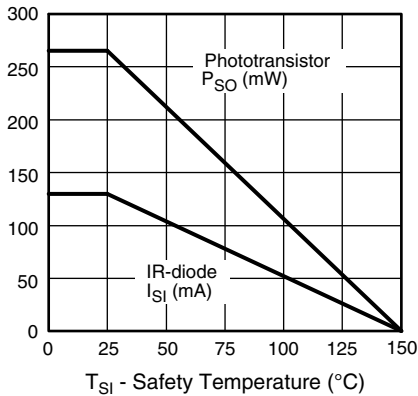


Fig. 4 - Derating Diagram

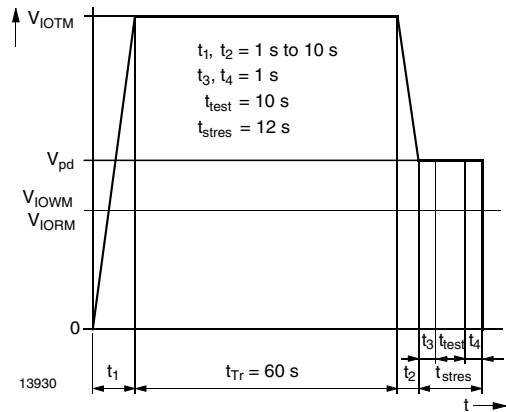


Fig. 5 - Test Pulse Diagram for Sample Test according to DIN EN 60747-5-5

TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

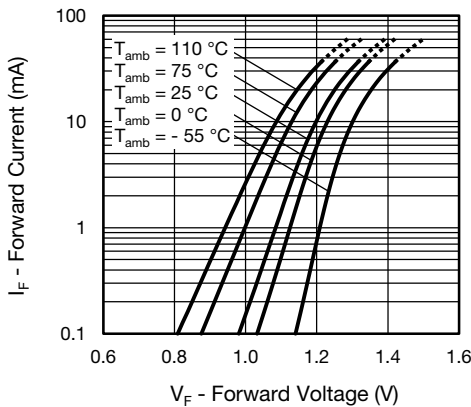


Fig. 6 - Forward Voltage vs. Forward Current

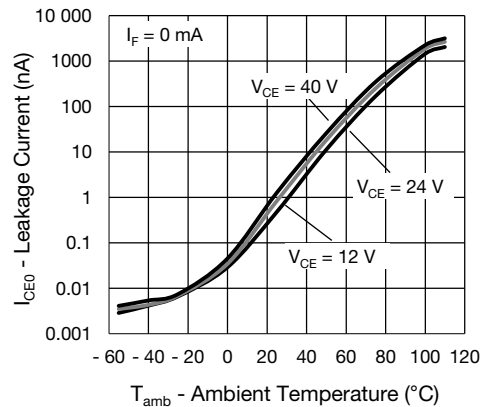


Fig. 8 - Collector Emitter Current vs. Ambient Temperature

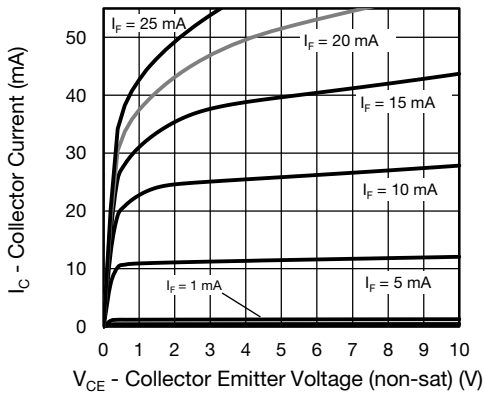


Fig. 7 - Collector Current vs. Collector Emitter Voltage (non-saturated)

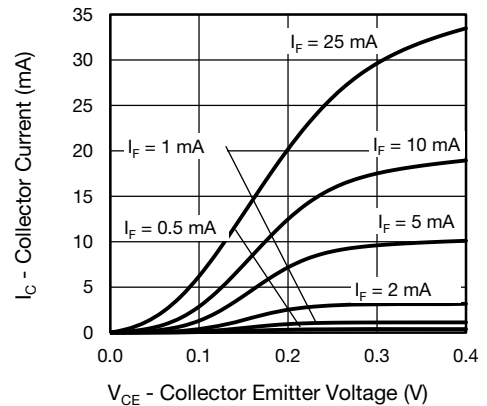


Fig. 9 - Collector Current vs. Collector Emitter Voltage (saturated)

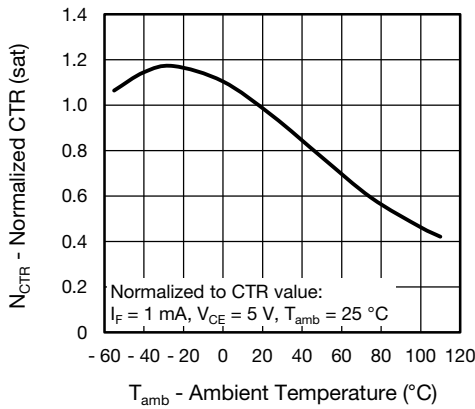


Fig. 10 - Normalized Current Transfer Ratio vs. Ambient Temperature (saturated)

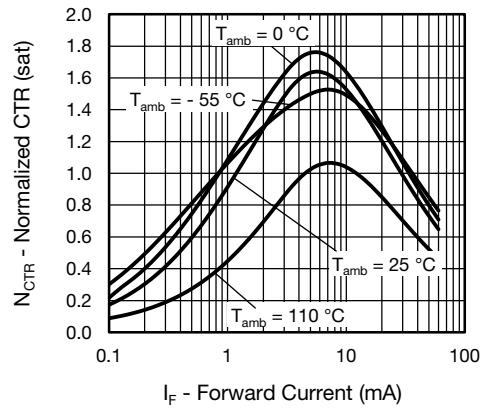


Fig. 13 - Current Transfer Ratio vs. Forward Current (non-saturated) Normalized to 1 mA at 25 °C

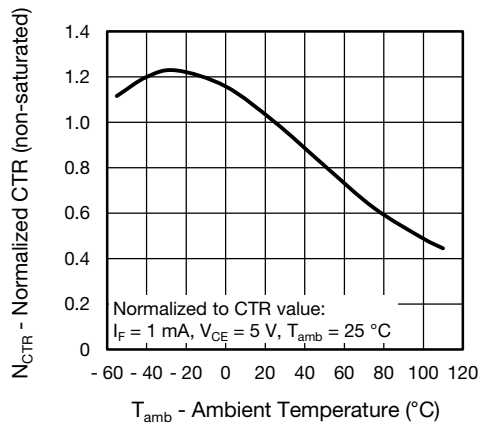


Fig. 11 - Normalized Current Transfer Ratio vs. Ambient Temperature (non-saturated)

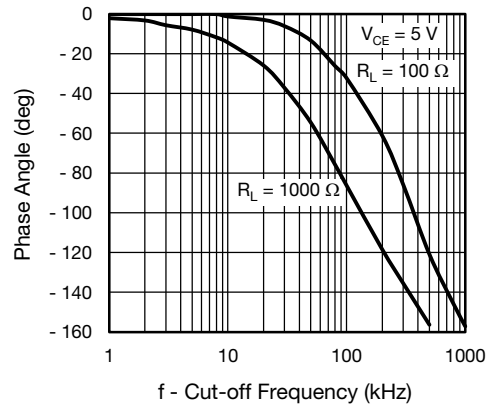


Fig. 14 - f_{CTR} vs. Phase Angle

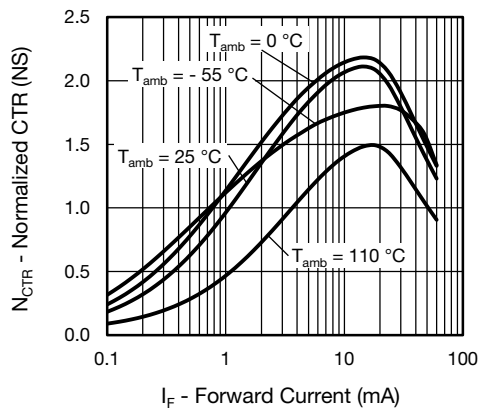


Fig. 12 - Current Transfer Ratio vs. Forward Current (saturated) Normalized to 1 mA at 25 °C

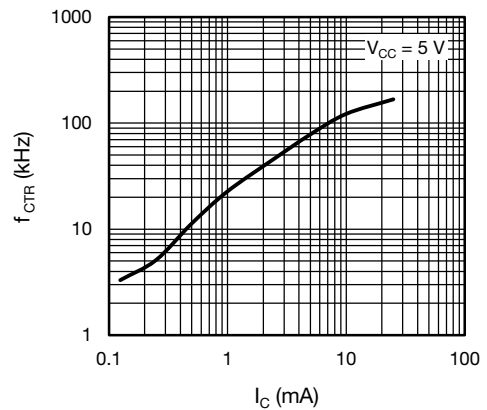


Fig. 15 - Cut-off Frequency (-3 dB) vs. Collector Current



Fig. 16 - Switching Time vs. Load Resistance

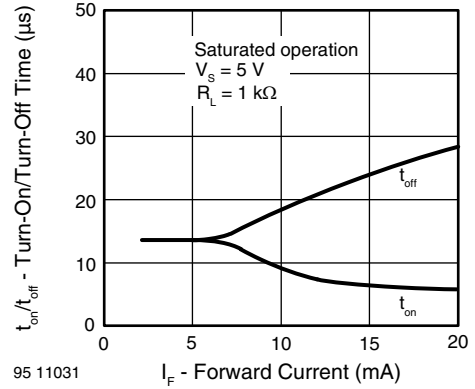


Fig. 18 - Turn-On/Turn-Off Time vs. Forward Current

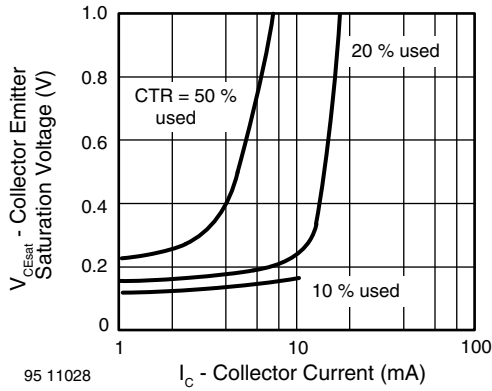


Fig. 17 - Collector Emitter Saturation Voltage vs. Collector Current

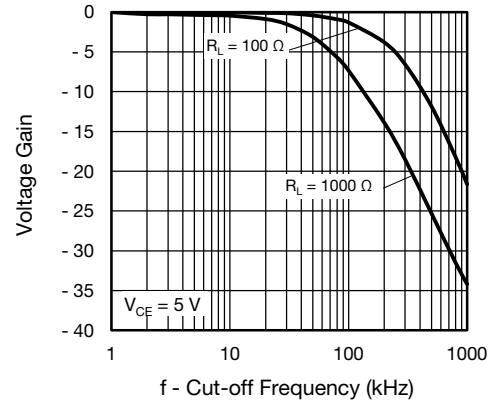
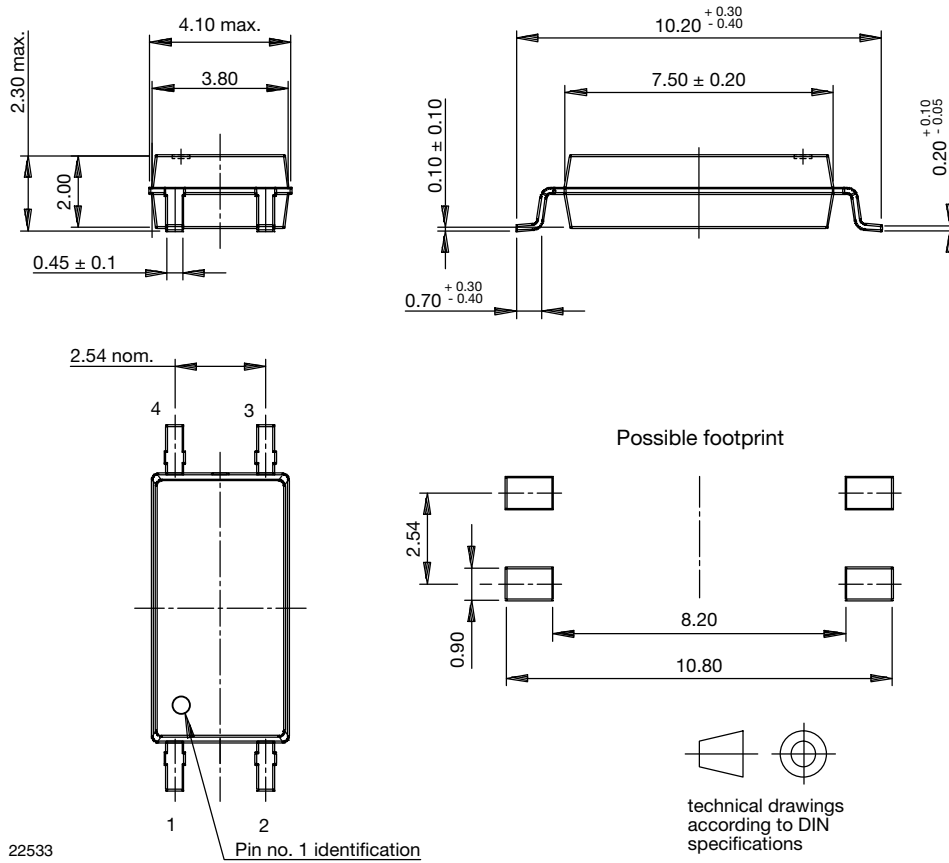
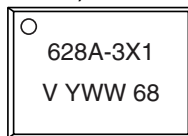


Fig. 19 - Voltage Gain vs. Cut-off Frequency

PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING (example of VOL628A-3X001T)



Notes

- Only option 1 is reflected in the package marking with the characters "X1".
- Tape and reel suffix (T) is not part of the package marking.

TAPE AND REEL DIMENSIONS in millimeters

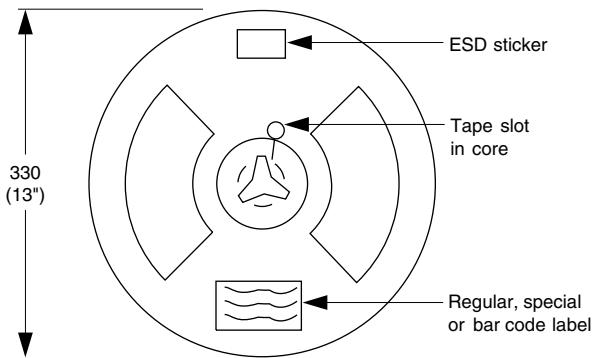


Fig. 20 - Reel Dimensions (3000 units per reel)

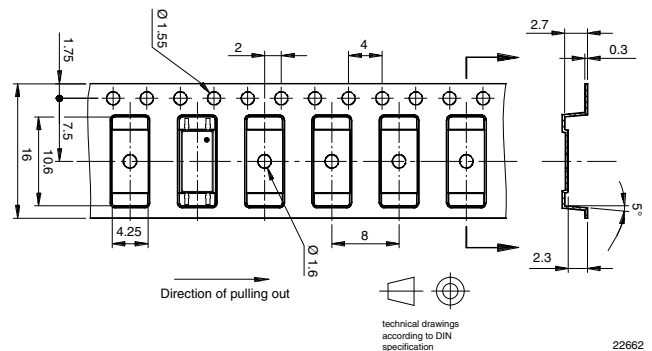


Fig. 21 - Tape Dimensions



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9